

# Silicon NPN Phototransistor

## Version 1.3

### SFH 309 FA



#### Features:

- **Spectral range of sensitivity:** (typ) 730 ... 1120 nm
- **Package:** 3mm Radial (T 1), Epoxy
- **Special:** High photosensitivity
- High linearity
- Available in groups

#### Applications

- Photointerrupters
- Industrial electronics
- For control and drive circuits

#### Ordering Information

Type:	Photocurrent $I_{PCE}$ [ $\mu$ A] $\lambda = 950 \text{ nm}$ , $E_e = 0.5 \text{ mW/cm}^2$ , $V_{CE} = 5 \text{ V}$	Ordering Code
SFH 309 FA	400 ... 5000	Q62702P0941
SFH 309 FA-3/4	630 ... 2000	Q62702P3590
SFH 309 FA-4	1000 ... 2000	Q62702P0178
SFH 309 FA-4/5	1000 ... 3200	Q62702P3591
SFH 309 FA-5	1600 ... 3200	Q62702P0180
SFH 309 FA-5/6	1600 ... 5000	Q62702P5199

*Note:* Only one bin within one packing unit (variation less than 2:1)

**Maximum Ratings** ( $T_A = 25\text{ °C}$ )

Parameter	Symbol	Values	Unit
Operating and storage temperature range	$T_{op}; T_{stg}$	-40 ... 100	°C
Collector-emitter voltage	$V_{CE}$	35	V
Collector current	$I_C$	15	mA
Collector surge current ( $\tau < 10\ \mu\text{s}$ )	$I_{CS}$	75	mA
Total Power dissipation	$P_{tot}$	165	mW
Thermal resistance	$R_{thJA}$	450	K / W
ESD withstand voltage (acc. to ANSI/ ESDA/ JEDEC JS-001 - HBM)	$V_{ESD}$	2000	V

**Characteristics** ( $T_A = 25\text{ °C}$ )

Parameter		Symbol	Values	Unit
Wavelength of max. sensitivity	(typ)	$\lambda_{S\ max}$	900	nm
Spectral range of sensitivity	(typ)	$\lambda_{10\%}$	(typ) 730 ... 1120	nm
Radiant sensitive area ( $\varnothing 220\ \mu\text{m}$ )	(typ)	A	0.038	mm <sup>2</sup>
Dimensions of chip area	(typ)	L x W	(typ) 0.45 x 0.45	mm x mm
Distance chip front to case surface	(min ... max)	H	(min ... max) 2.4 ... 2.8	mm
Half angle	(typ)	$\varphi$	$\pm 12$	°
Capacitance ( $V_{CE} = 0\ \text{V}$ , $f = 1\ \text{MHz}$ , $E = 0$ )	(typ)	$C_{CE}$	5	pF
Dark current ( $V_{CE} = 20\ \text{V}$ , $E = 0$ )	(typ (max))	$I_{CE0}$	1 ( $\leq 50$ )	nA

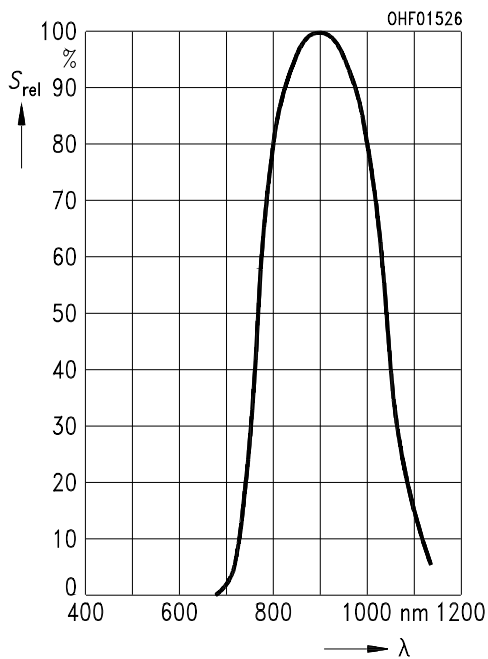
Grouping ( $T_A = 25\text{ }^\circ\text{C}$ ,  $\lambda = 950\text{ nm}$ )

Group	Min Photocurrent $E_e = 0.5\text{ mW/cm}^2$ , $V_{CE} = 5\text{ V}$ $I_{PCE, min}\text{ }[\mu\text{A}]$	Max Photocurrent $E_e = 0.5\text{ mW/cm}^2$ , $V_{CE} = 5\text{ V}$ $I_{PCE, max}\text{ }[\mu\text{A}]$	Rise and fall time $I_C = 1\text{ mA}$ , $V_{CC} = 5\text{ V}$ , $R_L = 1\text{ k}\Omega$ $t_r, t_f\text{ }[\mu\text{s}]$	Collector-emitter saturation voltage $I_C = I_{PCEmin} \times 0.3$ , $E_e = 0.5\text{ mW/cm}^2$ $V_{CEsat}\text{ }[\text{mV}]$
-2	400	800	5	200
-3	630	1250	6	200
-4	1000	2000	7	200
-5	1600	3200	8	200
-6	2500	5000	9	200

Note.:  $I_{PCEmin}$  is the min. photocurrent of the specified group.

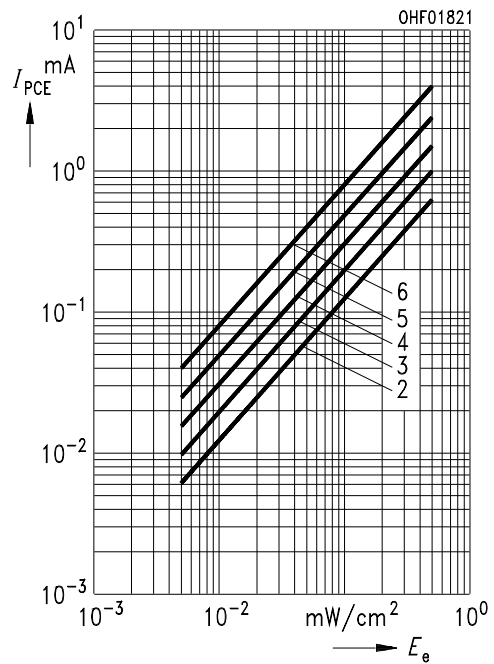
Relative Spectral Sensitivity <sup>1) page 9</sup>

$S_{rel} = f(\lambda)$



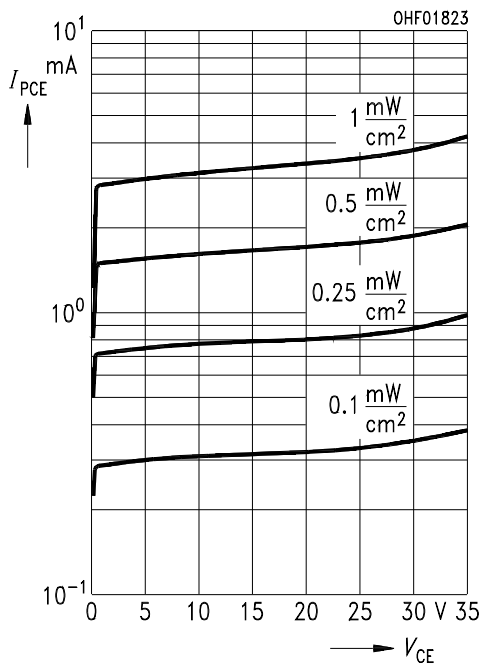
Photocurrent <sup>1) page 9</sup>

$I_{PCE} = f(E_e), V_{CE} = 5\text{ V}$



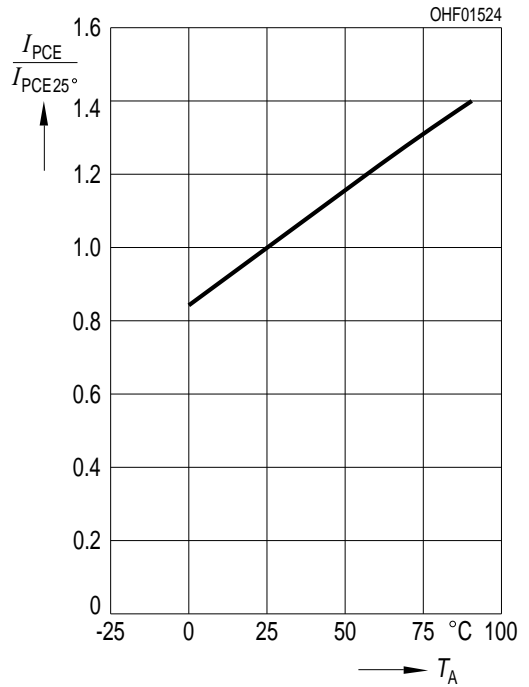
**Photocurrent** <sup>1) page 9</sup>

$I_{PCE} = f(V_{CE}), E_e = \text{Parameter}$



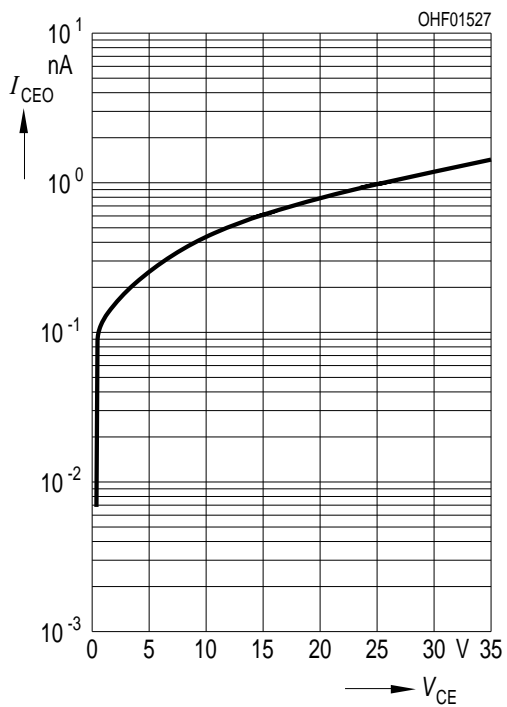
**Photocurrent** <sup>1) page 9</sup>

$I_{PCE} / I_{PCE}(25^\circ\text{C}) = f(T_A), V_{CE} = 5 \text{ V}$



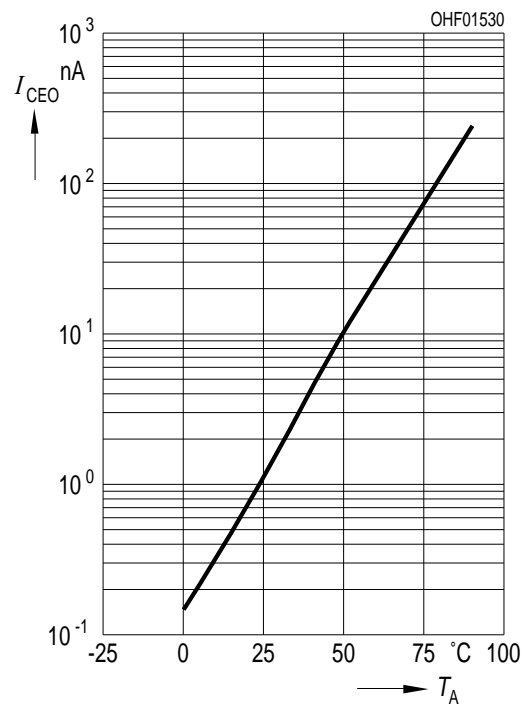
**Dark Current** <sup>1) page 9</sup>

$I_{CEO} = f(V_{CE}), E = 0$



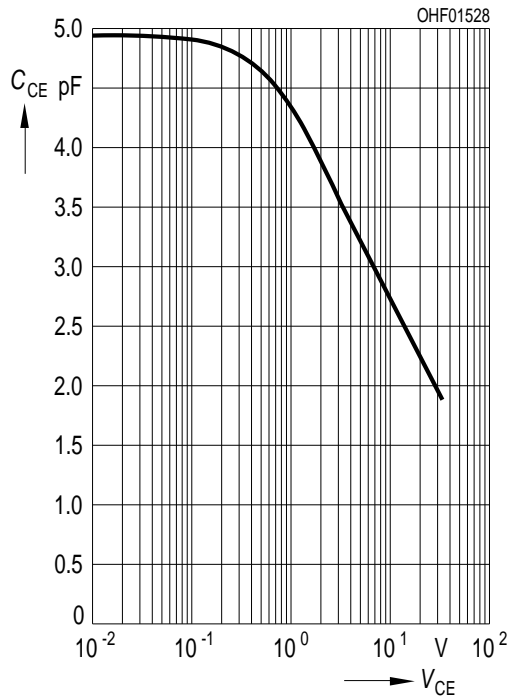
**Dark Current** <sup>1) page 9</sup>

$I_{CEO} = f(T_A), V_{CE} = 20 \text{ V}, E = 0$



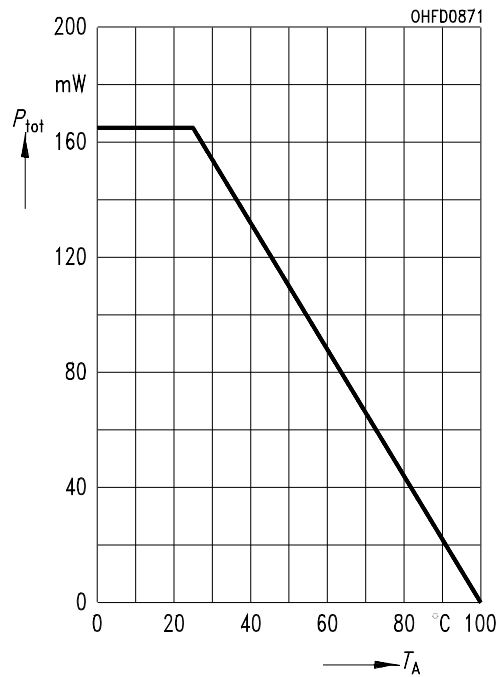
**Collector-Emitter Capacitance** <sup>1) page 9</sup>

$C_{CE} = f(V_{CE}), f = 1 \text{ MHz}, E = 0$



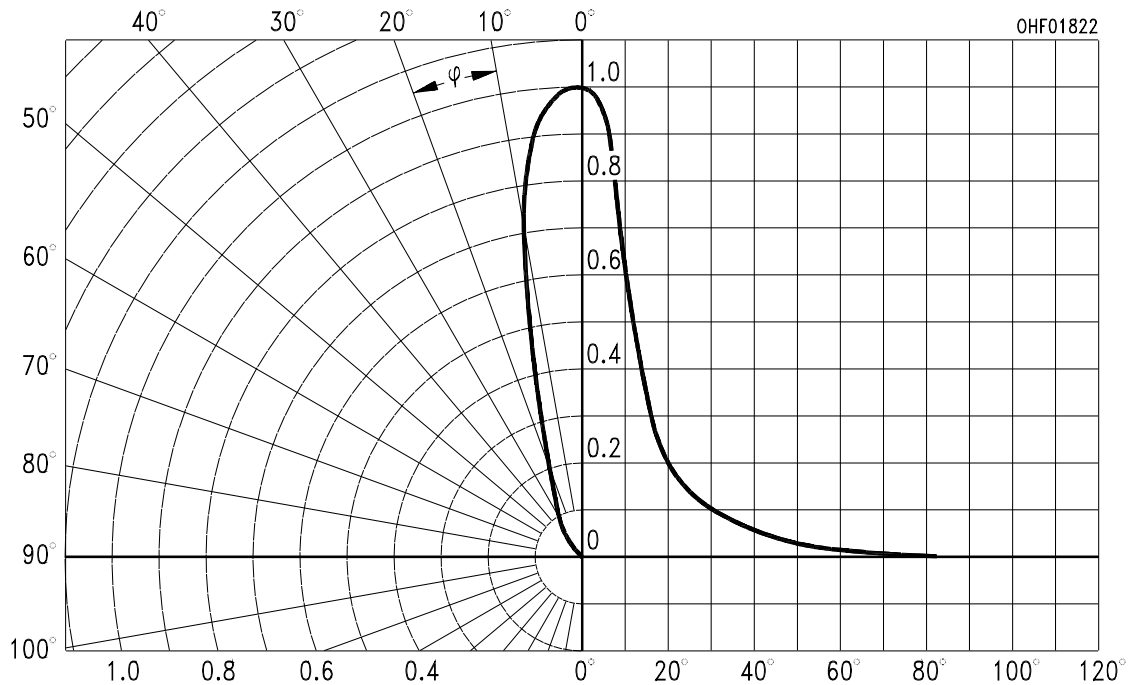
**Power Consumption**

$P_{tot} = f(T_A)$

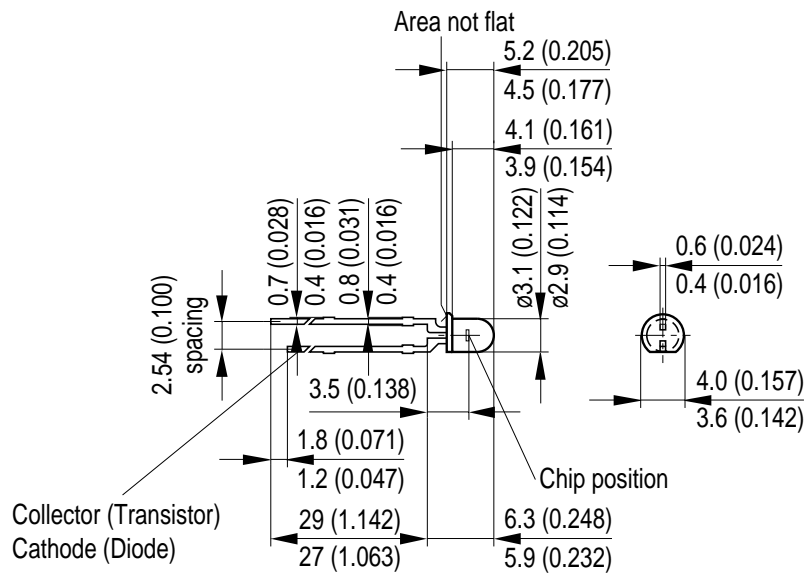


**Directional Characteristics** <sup>1) page 9</sup>

$S_{rel} = f(\phi)$



## Package Outline



*Dimensions in mm (inch).*

**Package**

3mm Radial (T 1), Epoxy

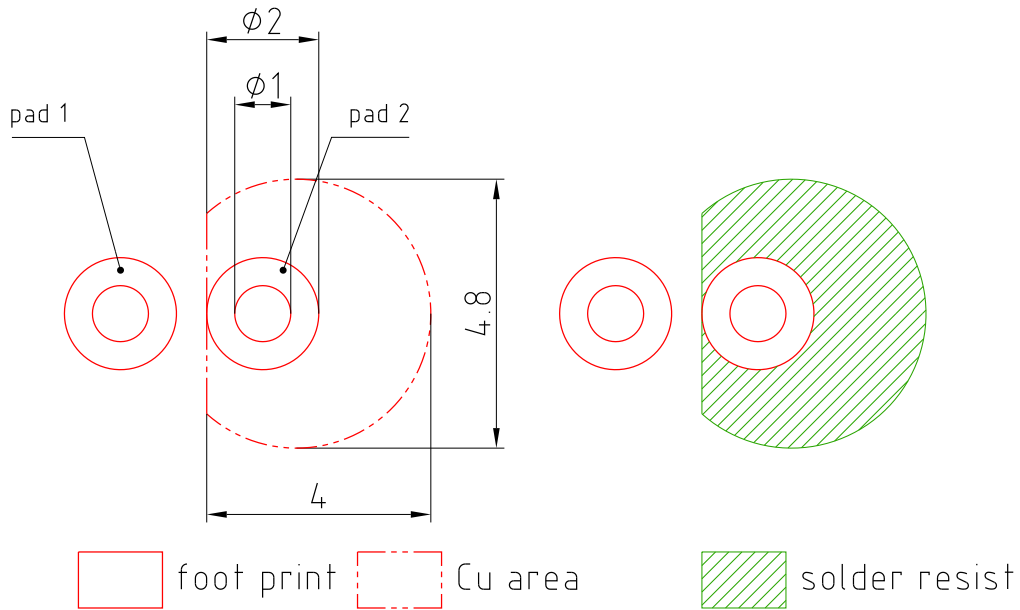
**Approximate Weight:**

0.2 g

**Note**

Packing information is available on the internet (online product catalog).

**Recommended Solder Pad**



E062.3010.188-01

Dimensions in mm.

**Note:**

pad 1: emitter

**TTW Soldering**

IEC-61760-1 TTW



**Disclaimer**

Language english will prevail in case of any discrepancies or deviations between the two language wordings.

**Attention please!**

The information describes the type of component and shall not be considered as assured characteristics.

Terms of delivery and rights to change design reserved. Due to technical requirements components may contain dangerous substances.

For information on the types in question please contact our Sales Organization.

If printed or downloaded, please find the latest version in the Internet.

**Packing**

Please use the recycling operators known to you. We can also help you – get in touch with your nearest sales office.

By agreement we will take packing material back, if it is sorted. You must bear the costs of transport. For packing material that is returned to us unsorted or which we are not obliged to accept, we shall have to invoice you for any costs incurred.

**Components used in life-support devices or systems must be expressly authorized for such purpose!**

Critical components\* may only be used in life-support devices\*\* or systems with the express written approval of OSRAM OS.

\*) A critical component is a component used in a life-support device or system whose failure can reasonably be expected to cause the failure of that life-support device or system, or to affect its safety or the effectiveness of that device or system.

\*\*) Life support devices or systems are intended (a) to be implanted in the human body, or (b) to support and/or maintain and sustain human life. If they fail, it is reasonable to assume that the health and the life of the user may be endangered.



**Glossary**

- <sup>1)</sup> **Typical Values:** Due to the special conditions of the manufacturing processes of LED, the typical data or calculated correlations of technical parameters can only reflect statistical figures. These do not necessarily correspond to the actual parameters of each single product, which could differ from the typical data and calculated correlations or the typical characteristic line. If requested, e.g. because of technical improvements, these typ. data will be changed without any further notice.

**Published by OSRAM Opto Semiconductors GmbH**  
**Leibnizstraße 4, D-93055 Regensburg**  
**www.osram-os.com © All Rights Reserved.**

EU RoHS and China RoHS compliant product



此产品符合欧盟 RoHS 指令的要求；  
按照中国的相关法规和标准，不含有毒有害物质或元素。

## Данный компонент на территории Российской Федерации

### Вы можете приобрести в компании MosChip.

Для оперативного оформления запроса Вам необходимо перейти по данной ссылке:

<http://moschip.ru/get-element>

Вы можете разместить у нас заказ для любого Вашего проекта, будь то серийное производство или разработка единичного прибора.

В нашем ассортименте представлены ведущие мировые производители активных и пассивных электронных компонентов.

Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

### Офис по работе с юридическими лицами:

105318, г.Москва, ул.Щербаковская д.3, офис 1107, 1118, ДЦ «Щербаковский»

Телефон: +7 495 668-12-70 (многоканальный)

Факс: +7 495 668-12-70 (доб.304)

E-mail: [info@moschip.ru](mailto:info@moschip.ru)

Skype отдела продаж:

moschip.ru

moschip.ru\_4

moschip.ru\_6

moschip.ru\_9